Surface Mount PIN Diode Limiter LM401102-Q-C-301 Series Datasheet



Features

- Surface Mount Limiter in Compact Outline: 8mm L x 5mm W x 2.5 mm H
- Incorporates PIN Limiter & Schottky Diodes, D.C. Blocks & D.C. Return
- Higher Average Power Handling than Plastic (100 W C.W. Power)
- Lower Insertion Loss (0.3 dB) & Lower Flat Leakage Power (18 dBm)
- · RoHS Compliant



Description

The LM401102-Q-C-301 Surface Mount Silicon PIN Diode Limiter is manufactured using Aeroflex / Metelics proven hybrid manufacturing process incorporating PIN Diodes and passive devices integrated within a ceramic substrate. This low profile, compact, surface mount component, (8mm L x 5mm W x 2.5 mm H) offers superior low and high signal performance to comparable MMIC devices in QFN packages. The Limiter Modules are designed to optimize small signal insertion loss, (N.F.) and high signal flat leakage performance in a compact, surface mount package.

Using PIN Diodes with lower thermal resistance (< 15 °C/W), and a de-coupled Schottky detector network as a current source, RF C.W. incident power levels of +50 dBm and RF peak incident power levels of +63 dBm @ 25 μ S RF pulse width, 10% duty cycle are very achievable. In addition, this design concept provides lower flat leakage power (< + 18 dBm) and lower spike leakage energy (< 0.4 Ergs) for superior LNA protection. The LM401102-Q-C-301 limiter can be configured without a D.C. block on the output to obtain lower flat leakage power, (< +18 dBm) with an external ZBD schottky diode. This Limiter Part Number is LM401102-Q-B-301.

Applications

These LM401102-Q-C-301 and LM401102-Q-B-301 Limiters are ideal for octave band Radar applications, from 400-1,000 MHz, requiring high volume, surface mount, solder re-flow manufacturing. These products are durable, reliable, and capable of meeting all military, commercial, and industrial environments. The devices are fully RoHS compliant and are available in tube or tape-reel.

Environmental Capabilities

The LM401102-Q-C-301 and LM401102-Q-B-301 Limiters are capable of meeting the environmental requirements of MIL-STD-750 and MIL-STD-202.

ESD Rating

PIN Diode Limiters are susceptible to ESD conditions as with all semiconductors. The ESD rating for this device is Class 0, HBM. The moisture sensitivity level rating for this device is MSL 2.



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LM401102-Q-C-301 & LM401102-Q-B-301 Electrical Specifications @ $Zo = 50 \Omega$, TA=+ 25 °C (Unless Otherwise Defined)

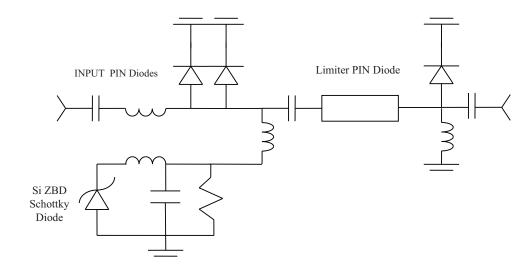
Parameter	Symbol	Units	Test Conditions	Minimum Value	Typical Value	Maximum Value
Frequency	F	MHz	Swept Frequency	350	400 - 1000	1500
Insertion Loss	ΙL	dB	Swept Frequency Po = 0 dBm		-0.3	-0.5
Return Loss	R _L	dB	Swept Frequency Po = 0 dBm	-15	-17	
Input Compression Power	P1dB	dBm	Swept Frequency	+8	+10	+12
2nd Harmonic	2F _o	dBc	Po = 0 dBm Fo = 2 GHz	45	50	
Peak Incident Power	P _{inc} (Pk)	dBm	RF Pulse Width = 1μ S, 0.001 duty		+60	+60
C.W. Incident Power	P _{inc} (CW)	dBm	Swept Frequency		+50	+51
Flat Leakage Power	P _f	dBm	+50 dBm, RF Pulse Width = 1µS, 0.001 duty		+18	+21
Spike Leakage Energy	E _S	Ergs	+50 dBm, RF Pulse Width = 1μS, 0.001 duty		0.4	0.5
Recovery Time	T _r	ηS	(50% Trailing RF Pulse – 1dB IL) + 50 dBm, RF Pulse Width = 1µS, 0.001 duty		5	10

Absolute Maximum Ratings @ $T_A = + 25$ °C (Unless Otherwise Defined)

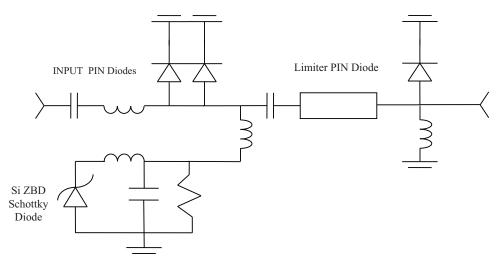
Parameter	Absolute Maximum Value	
Operating Temperature	-65 °C to +125 °C	
Storage Temperature	-65 °C to +150 °C	
Junction Temperature	+175 °C	
RF C.W. Incident Power @ +85 °C Source & Load VSWR < 1.2:1	+50 dBm	
RF Peak. Incident Power @ +85 °C Source & Load VSWR < 1.2:1	$+63$ dBm, RF Pulse Width $=25~\mu\text{S}, 5\%$ duty cycle $+60$ dBm, RF Pulse Width $=50\mu\text{S}, 1\%$ duty cycle	
Insertion Loss Rate of Change with Operating Temperature	- 0.0025 dB / ° C	
θjc C.W. Thermal Resistance (Junction to Case)	8 ° C/W	
Assembly Temperature	+260 °C for 10 Seconds	



LM401102-Q-C-301 Limiter Schematic



LM401102-Q-B-301 Limiter Schematic



Part Number Ordering Information:

Part Number	art Number DC Blocking Configuration	
LM401102-Q-C-301-T	D.C. Blocks on Input & Output	Tube Packaging
LM401102-Q-C-301-R	D.C. Blocks on Input & Output	Tape-Reel Packaging
LM401102-Q-C-301-E	D.C. Blocks on Input & Output	RF Evaluation Board
LM401102-Q-B-301-T	D.C. Block on Input Only	Tube Packaging
LM401102-Q-B-301-R	D.C. Block on Input Only	Tape-Reel Packaging
LM401102-Q-B-301-E	D.C. Block on Input Only	RF Evaluation Board



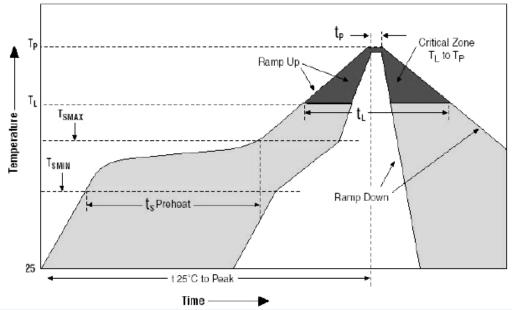
Assembly Instructions

TheLM401102-Q-C-301 Limiters are capable of being placed onto circuit boards with pick and place manufacturing equipment from tube or tape-reel dispensing. The devices are attached to the circuit board using conventional solder re-flow or wave soldering procedures with RoHS type or Sn 63 / Pb 37 type solders per Table I and Graph I Time-Temperature recommended profile.

Table 1: Time-Temperature Profile for Sn 60/Pb40 or RoHS Type Solders

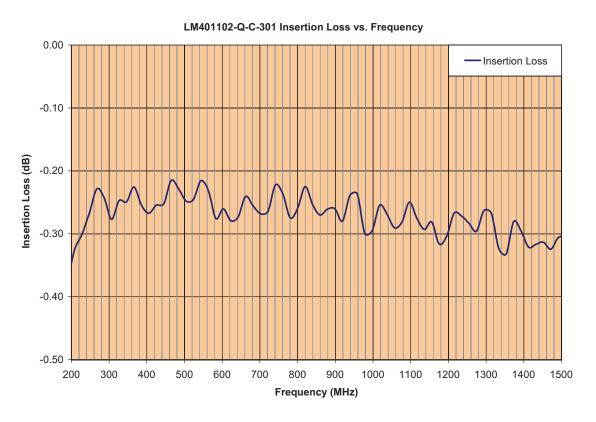
Profile Feature	Sn-Pb Eutectic Assembly	Pb-Free Assembly	
Average ramp-up rate (T _L to T _P)	3°C/second maximum	3°C/second maximum	
Preheat - Temperature Minimum (T _{SMIN}) - Temperature Maximum (T _{SMAX}) - Time (Minimum to maximum) (t _S)	100°C 150°C 60-120 seconds	150°C 200°C 60-180 seconds	
T _{SMAX} to T _L - Ramp-up Rate		3°C/second maximum	
Time Maintauined above: - Temperature (T _L) - Time (t _L)	183°C 60-150 seconds	217°C 60-150 seconds	
Peak Temperature (T _P)	225 +0 / -5°C	245 +0/-5°C	
Time within 5°C of actual Peak Temperature (T _P)	10-30 seconds	20-40 seconds	
Ramp-down Rate	6°C/second maximum	6°C/second maximum	
Time 25°C to Peak Temperature	6 minutes maximum	8 minutes maximum	

Graph1: Solder Re-Flow Time-Temperature Function

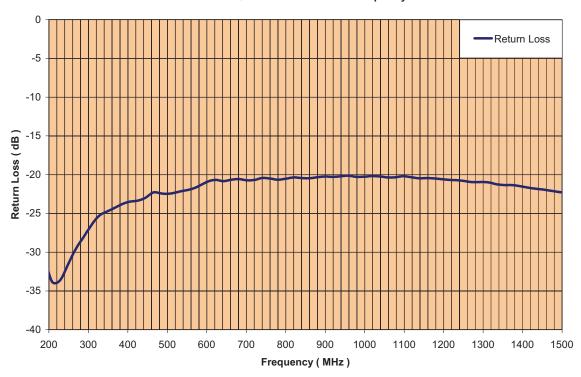




LM401102-Q-C-301 Typical RF Small Signal Performance @ +25 °C



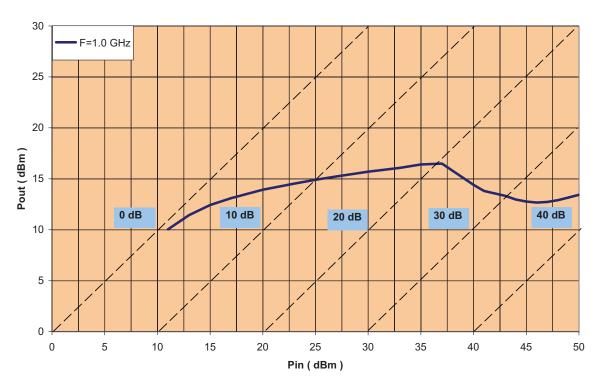
LM401102-Q-C-301 Return Loss vs Frequency



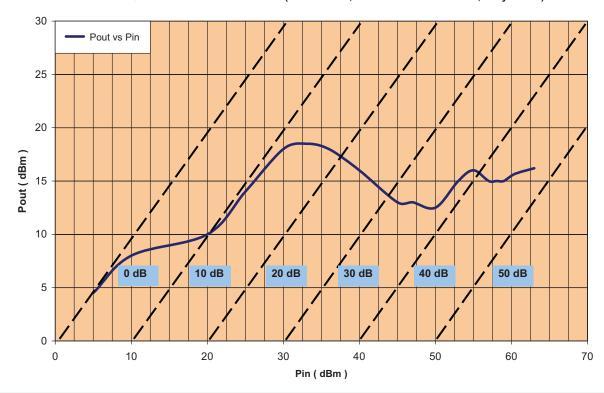


LM401102-Q-C-301 High Signal Parametric Data

LM401102-Q-C-301 Pout vs Pin C.W. Performance

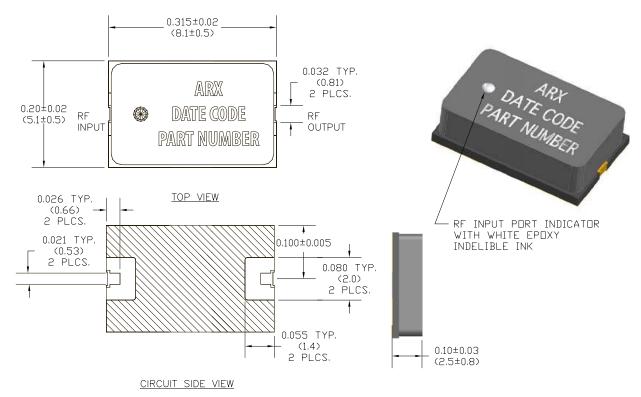


LM401102-Q-C-301 Peak Power Function (F = 1.0 GHz, RF Pulse Width = 25 uS, Duty = 1 %)





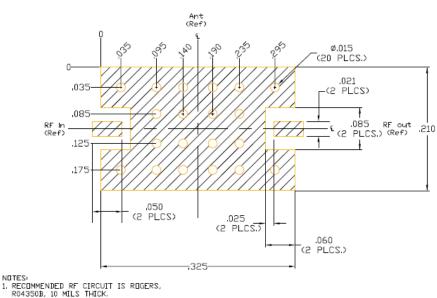
LM401102-Q-C-301 Outline Drawing, Case Style 301, (CS301)



NOTES:

- SUBSTRATE MATERIAL: 20 MIL THICK ALUMINA NITRIDE (ALN) RF COVER: BLACK CERAMIC. TOP SIDE AND BACKSIDE METALLIZATION:
- 3. DIMENSION IN PARENTHESIS ARE IN MM.

RF Circuit Solder Footprint for Case Style 301 (CS 301)



Thatched Area is RF, D.C., and Thermal Ground. Vias should be solid copper fill and gold plated for optimum heat transfer from backside of limiter module through Circuit Vias to metal thermal ground.



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Our passion for performance is defined by three attributes represented by these three icons: solution-minded, performance-driven and customer-focused.